



Commissioner of Patents and Trademarks Washington, D.C. 20231

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Subject:

Serial No. 09/759,908 01/16/01

Y.H. Chen, J.C. Twu, W. Chang

MULTILAYER INTERFACE IN COPPER CMP FOR LOW K DIELECTRIC

Grp. Art Unit: 2812

INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation
In An Application.

The following Patents and/or Publications are submitted to comply with the duty of disclosure under CFR 1.97-1.99 and 37 CFR 1.56. Copies of each document is included herewith.

U.S. Patent 6,004,188 to Roy, "Method for Forming Copper Damascene Structures by Using a Dual CMP Barrier Layer", describes a method for forming copper damascene structures by using a dual chemical mechanical polish (CMP) barrier layer.

TSMC-99-105

- U.S. Patent 6,010,962 to Liu et al., "Copper Chemical-Mechanical-Polishing (CMP) Dishing", discloses a Chemical-Mechanical Polish (CMP) planarizing method that avoids dishing.
- U.S. Patent 5,512,163 to Warfield, "Method for Forming a Planarization Etch Stop", discloses a mechanical polishing method that uses an etch-stop layer consisting of a metal and grit material, i.e., diamond powder, over a conductive layer.
- U.S. Patent 5,854,133 to Hachiya et al., "Method for Manufacturing a Semiconductor Device", discloses a chemical mechanical polish (CMP) planarizing method that utilizes a polysilicon film as an etch-stop.

Sincerely

Stephen B. Ackerman, Reg. No. 37761

Form PTO-1449 TSMC-97-105 759,908 INFORMATION DISCLOSURE CITATION Y.H. Chen IN AN APPLICATION מרסטס גרו טראו O Pusceporal shoots il nocossary) 2812 U. S. PATENT DOCUMENTS DOCATION HOMBEN DATE HULE Y WTROPULTE CLUE SUBCLUZE 004188122199 451 010962 438 687 205 109 438 692 FOREIGN PATENT DOCUMENTS Trinslitten DOCUMENT NUMBER OUTE COUNTRY CUSS. \$U8CU33 YES . OTHER DOCUMENTS (Including Luttor, Milo, Dalo, Porting Pagos, Elc.) COMMEN DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.